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ON Semiconductor®

RURP1560-F085 15A, 600V Ultrafast Rectifier

Features

- High Speed Switching (t_{rr}=52ns(Typ.) @ I_F=15A)
- Low Forward Voltage(V_F=1.5V(Max.) @ I_F=15A)
- · Avalanche Energy Rated
- · AEC-Q101 Qualified

Applications

- · Automotive DCDC converter
- · Automotive On Board Charger
- · Switching Power Supply
- · Power Switching Circuits

15A, 600V Ultrafast Rectifier

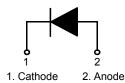
The RURP1560-F085 is an ultrafast diode with soft recovery characteristics(trr < 70ns). It has a low forward voltage drop and is of planar, silicon nitride assivated, ion-implanted, epitaxial construction.

This device is intended for use as an energy steering / clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor.

Pin Assignments



TO-220-2L



Cathode

Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V_{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current @ T _C = 25°C	15	Α	
I _{FSM}	Non-repetitive Peak Surge Current	200	Α	
E _{AVL}	Avalanche Energy (1A, 40mH)	20	mJ	
T _{J,} T _{STG}	Operating Junction and Storage Temperature	- 55 to +175	°C	

Thermal Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Max	Units
$R_{ heta JC}$	Maximum Thermal Resistance, Junction to Case	1	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	85	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Package Reel Size Tape Width		Quantity	
RURP1560	RURP1560-F085	TO-220-2L	-	-	50	

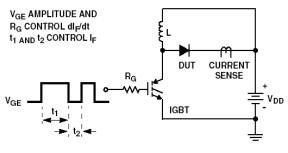
Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Conditions		Min.	Тур.	Max	Units
I _R	Instantaneous Reverse Current	V _R = 600V	T _C = 25 °C	-	-	100	uA
			T _C = 175 °C	-	-	1	mA
V _{FM} ¹	Instantaneous Forward Voltage	I _F = 15A	T _C = 25 °C T _C = 175 °C	-	1.24 1.0	1.5 1.2	V V
t _{rr} ²	Reverse Recovery Time	I_F =1A, di/dt = 100A/ μ s, V_{CC} = 390V	T _C = 25 °C	-	32	55	ns
		I_F =15A, di/dt = 100A/ μ s, V_{CC} = 390V	T _C = 25 °C T _C = 175 °C	-	52 220	70 -	ns ns
t _a t _b Q _{rr}	Reverse Recovery Time Reverse Recovery Charge	I_F =15A, di/dt = 100A/ μ s, V_{CC} = 390V	T _C = 25 °C	- - -	28 24 73	- - -	ns ns nC
E _{AVL}	Avalanche Energy	I _{AV} =1.0A,L = 40mH		20	-	-	mJ

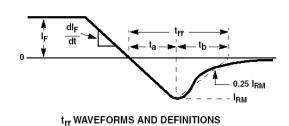
Notes:

- 1. Pulse : Test Pulse width = $300\mu s$, Duty Cycle = 2%
- 2. Guaranteed by design

Test Circuit and Waveforms



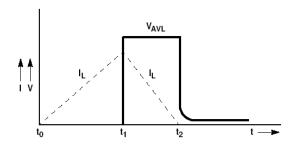
t_{rr} TEST CIRCUIT



$$\begin{split} I_{MAX} &= 1A \\ L &= 40mH \\ R &< 0.1\Omega \\ E_{AVL} &= 1/2LI^2 \left[V_{R(AVL)}/(V_{R(AVL)} - V_{DD}) \right] \\ Q_1 &= IGBT \left(BV_{CES} > DUT \, V_{R(AVL)} \right) \\ &\qquad \qquad L \\ &\qquad \qquad R \\ &\qquad \qquad CURRENT \\ SENSE \end{split}$$

AVALANCHE ENERGY TEST CIRCUIT

DUT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

 V_{DD}

 V_{DD}

- o

Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop vs. Forward Current

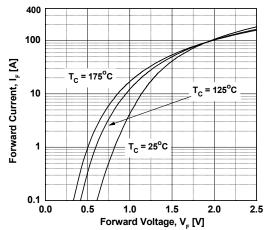


Figure 3. Typical Junction Capacitance

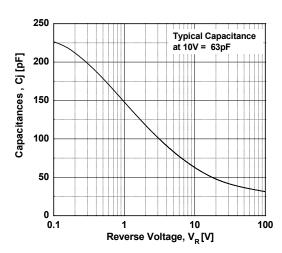


Figure 5. Typical Reverse Recovery Current vs. di/dt

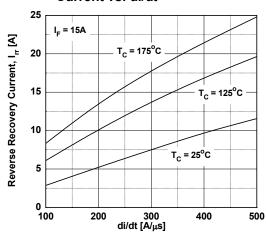


Figure 2. Typical Reverse Current vs. Reverse Voltage

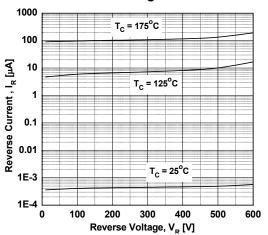


Figure 4. Typical Reverse Recovery Time vs. di/dt

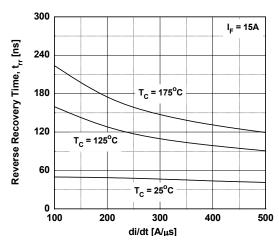
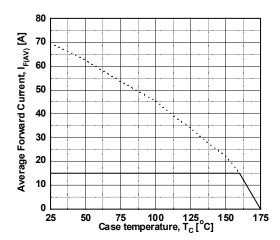


Figure 6. Forward Current Derating Curve



Typical Performance Characteristics (Continued)

Figure 7. Reverse Recovery Charge

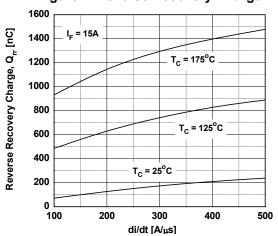
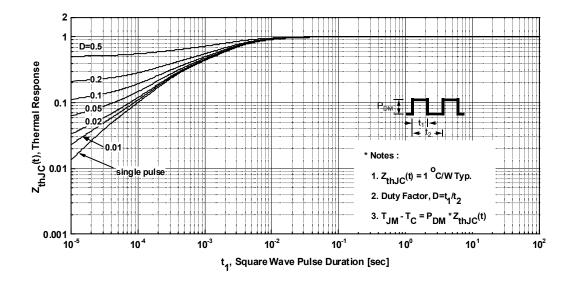
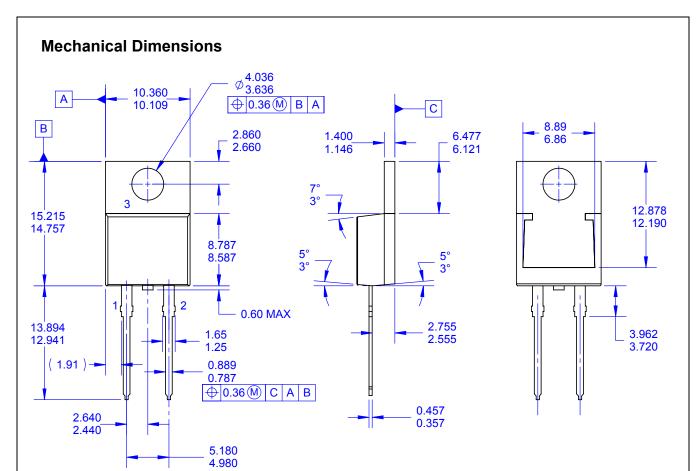
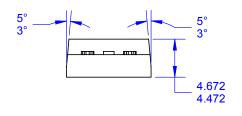


Figure 8. Transient Thermal Response Curve







NOTES:

- A. PACKAGE REFERENCE: JEDEC TO220 VARIATION AC.

- VARIATION AC.
 B. ALL DIMENSIONS ARE IN MILLIMETERS.
 C. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
 D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
 E. DRAWING FILE NAME: TO220B02REV5

Dimensions in Millimeters

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